- Qualified for Automotive Applications
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates Up To 1 Mbit/s
- Low Standby Current . . . 1 μA Typical
- External Capacitors . . . $4 \times 0.1 \ \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Auto-Powerdown Feature Automatically Disables Drivers for Power Savings
- Applications
 - Battery-Powered, Hand-Held, and Portable Equipment
 - PDAs and Palmtop PCs
 - Notebooks, Sub-Notebooks, and Laptops
 - Digital Cameras
 - Mobile Phones and Wireless Devices

description/ordering information

SLLS616B - APRIL 2004 - REVISED APRIL 2008 **DB or PW PACKAGE** (TOP VIEW) EN 16 FORCEOFF 15 VCC C1+ [2 14 GND V+ 13 13 DOUT $C1 - \Pi 4$ 12 FORCEON C2+ [5 C2-Π6 11 DIN V− **Π**7 10 INVALID 9 ROUT RIN 8

The SN65C3221 consists of one line driver, one line receiver, and a dual charge-pump circuit with \pm 15-kV ESD protection pin to pin (serial-port connection pins, including GND). This device provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. This device operates at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If FORCEOFF is set low and EN is high, both the driver and receiver are shut off, and the supply current is reduced to 1 μ A. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The INVALID output notifies the user if an RS-232 signal is present at the receiver input. INVALID is high (valid data) if the receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μ s. See Figure 5 for receiver input levels.

т _А	PACKAGE [‡]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
40%C to 85%C	TSSOP (PW)	Reel of 2000	SN65C3221IPWRQ1	3221Q1
–40°C to 85°C	SSOP (DB)	Reel of 2000	SN65C3221IDBRQ	3221Q1

ORDERING INFORMATION[†]

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

[‡] Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.



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Function Tables

			EACH DRIVER		
		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
н	Н	Н	Х	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
н	L	Н	Yes	L	auto-powerdown enabled
L	L	н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

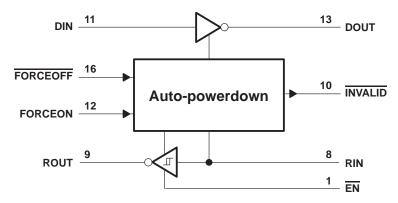
H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER

	INP	PUTS	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	Х	Н
н	L	х	L
Х	Н	Х	Z
Open	L	No	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC} (see Note 1) Positive output supply voltage range, V+ (see Note 1) Negative output supply voltage range, V- (see Note 1) Supply voltage difference, V+ - V- (see Note 1) Input voltage range, V _I : Driver (FORCEOFF, FORCEON, EN) Receiver Output voltage range, V _O : Driver Receiver (INVALID) Package thermal impedance, θ_{JA} (see Note 2 and Note 3) Operating virtual junction temperature, T ₁	$\begin{array}{cccc} -0.3 \ V \ to \ 7 \ V \\ 0.3 \ V \ to \ -7 \ V \\ 0.3 \ V \ to \ -7 \ V \\ 0.3 \ V \ to \ -7 \ V \\ 0.4 \ V \ to \ 6 \ V \\ 0.4 \ V \ to \ 5 \ V \\ 0.4 \ V \ to \ 5 \ V \\ 0.4 \ V \ to \ 5 \ V \\ 0.4 \ V \ to \ 13.2 \ V \\ 0.4 \ V \ to \ 13.2 \ V \\ 0.4 \ V \ to \ 13.2 \ V \\ 0.4 \ V \ to \ 13.2 \ V \\ 0.4 \ V \ to \ V_{CC} \ + \ 0.3 \ V \\ 0.4 \ V \ V_{CC} \ V \ V \ V \ V \ V \ V \ V \ V \ V \ $
Operating virtual junction temperature, T _J Storage temperature range, T _{stg}	150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

- 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 6)

				MIN	NOM	MAX	UNIT
	Currely welfage		V _{CC} = 3.3 V	3	3.3	3.6	N/
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	V
	Driver and control high-level input voltage	DIN, FORCEOFF, FORCEON, EN	$V_{CC} = 3.3 V$	2			V
VIH		DIN, FORCEOFF, FORCEON, EN	$V_{CC} = 5 V$	2.4			V
V_{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON, EN				0.8	V
VI	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
VI Receiver input voltage			-25		25	V	
TA	Operating free-air temperature			-40		85	°C
LOTE		0 0 V / 0 0 V 0 0 0 17 E 00	04 000 E 1		14		

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP‡	MAX	UNIT	
Ц	Input leakage current	FORCEOFF, FORCEON, EN			±0.01	±1	μΑ
		Auto-powerdown disabled No load, FORCEOFF and FORCE	No load, FORCEOFF and FORCEON at V_{CC}		0.3	1	mA
	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
lcc	(T _A = 25°C)	Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

[‡] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TES	T CONDITIONS	MIN	TYP†	MAX	UNIT	
∨он	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to GND,	DIN = GND	5	5.4		V	
VOL	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to GND,	DIN = V _{CC}	-5	-5.4		V	
Ιн	High-level input current	$V_{I} = V_{CC}$			±0.01	±1	μA	
١ _L	Low-level input current	V _I at GND			±0.01	±1	μA	
	o		V _{CC} = 3.6 V,	$V_{O} = 0 V$		±35	±60	
los	Short-circuit output current‡	V _{CC} = 5.5 V,	$V_{O} = 0 V$		±35	±75	mA	
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_{O} = \pm 2 V$	300	10M		Ω	
l _{off}	Output leakage current	FORCEOFF = GND	$V_{O} = -10 V \text{ to } +12 V,$ $V_{CC} = 3 V \text{ to } 3.6 V$			±25	μA	
			$V_{O} = \pm 10$ V, $V_{CC} = 4.5$ V to 5.5 V			±25		

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡] Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	-	TEST CONDITIONS		MIN	TYP†	MAX	UNIT
			C _L = 1000 pF		250			
	Maximum data rate (see Figure 1)	$R_L = 3 k\Omega$	C _L = 250 pF,	V_{CC} = 3 V to 4.5 V	1000			kbit/s
			C _L = 1000 pF,	V_{CC} = 4.5 V to 5.5 V	1000			
tsk(p)	Pulse skew§	$C_L = 150 \text{ pF}$ to 2500 pF	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega$,	See Figure 2		100		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V _{CC} = 3.3 V, R _L = 3 kΩ to 7 kΩ	C _L = 150 pF to 1000 pF		24		150	V/µs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

§ Pulse skew is defined as |tPLH - tPHL| of each channel of the same device.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

ESD protection

TERM	NAL		TVD	
NAME	NO.			UNIT
DOUT	13	НВМ	±15	kV



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RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	I _{OH} = -1 mA	V _{CC} -0.6 V	V _{CC} -0.1 V		V
VOL	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
N/	Desitive sains issue threaded a value of	V _{CC} = 3.3 V		1.6 2.4	V	
VIT+	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.9	2.4	V
	No weathing the factor for and the second state of the sec	$V_{CC} = 3.3 V$	0.6	1.1		
V _{IT} –	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.4		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT} _)			0.5		V
loff	Output leakage current	FORCEOFF = 0 V		±0.05	±10	μΑ
ri	Input resistance	$V_I = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4)

	PARAMETER	TEST CONDITIONS	ΜΙΝ ΤΥΡ [†] ΜΑΧ	UNIT
^t PLH	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 3	150	ns
^t PHL	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	150	ns
ten	Output enable time	C_L = 150 pF, R_L = 3 k Ω , See Figure 4	200	ns
t _{dis}	Output disable time	C_L = 150 pF, R_L = 3 k Ω , See Figure 4	200	ns
t _{sk(p)}	Pulse skew [‡]	See Figure 3	50	ns

[†] All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}$ C.

[‡]Pulse skew is defined as |tpLH - tpHL| of each channel of the same device.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

ESD protection

TERM	INAL	TEST CONDITIONS TY		
NAME NO.		TEST CONDITIONS		UNIT
RIN	8	НВМ	±15	kV



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AUTO-POWERDOWN SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CO	ONDITIONS	MIN	MAX	UNIT
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$		2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-2.7		V
V _{T(invalid)}	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-0.3	0.3	V
VOH	INVALID high-level output voltage	$\frac{I_{OH} = -1 \text{ mA}}{FORCEOFF} = V_{CC}$	DN = GND,	V _{CC} -0.6		V
V _{OL}	INVALID low-level output voltage	$I_{OL} = 1.6 \text{ mA}, \text{FORCEO}$ FORCEOFF = V_{CC}	DN = GND,		0.4	V

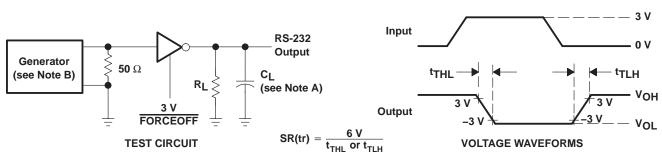
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	MIN TYP [†]	MAX	UNIT
^t valid	Propagation delay time, low- to high-level output	1		μs
^t invalid	Propagation delay time, high- to low-level output	30		μs
t _{en}	Supply enable time	100		μs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.



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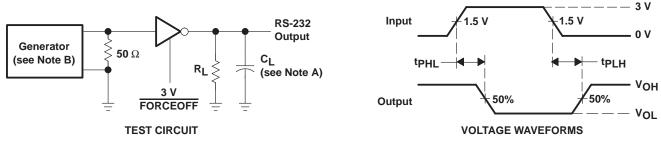


PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

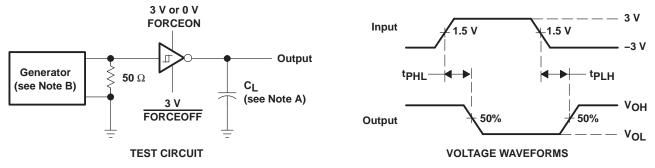
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



NOTES: A. CL includes probe and jig capacitance. B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew

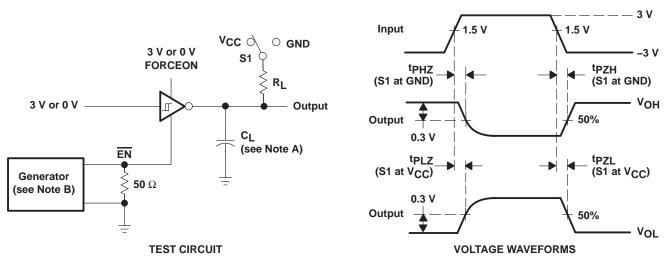


NOTES: A. C_L includes probe and jig capacitance. B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



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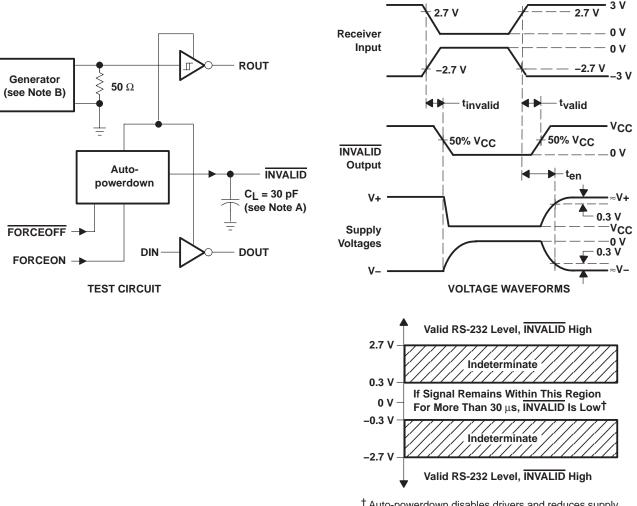
PARAMETER MEASUREMENT INFORMATION

- NOTES: A. $C_{\mbox{L}}$ includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 4. Receiver Enable and Disable Times



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PARAMETER MEASUREMENT INFORMATION

 † Auto-powerdown disables drivers and reduces supply current to 1 $\mu A.$

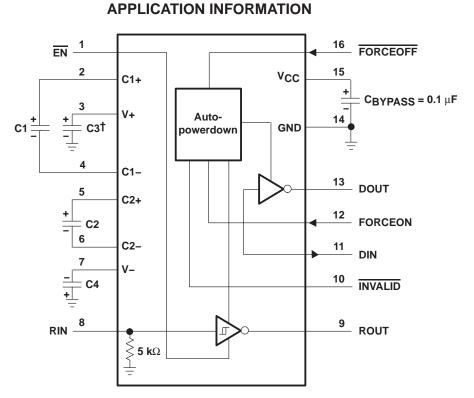
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 5. INVALID Propagation Delay Times and Driver Enabling Time



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† C3 can be connected to V_{CC} or GND. NOTE A: Resistor values shown are nominal.

V _{CC} vs CAPACITOR VALUES										
Vcc	C1	C2, C3, and C4								
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF								

Figure 6. Typical Operating Circuit and Capacitor Values





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65C3221IPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CB3221I	Samples
SN65C3221IPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CB3221I	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF SN65C3221-Q1 :

Catalog: SN65C3221

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C3221IPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65C3221IPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C3221IPWRG4Q1	TSSOP	PW	16	2000	356.0	356.0	35.0
SN65C3221IPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0

PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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